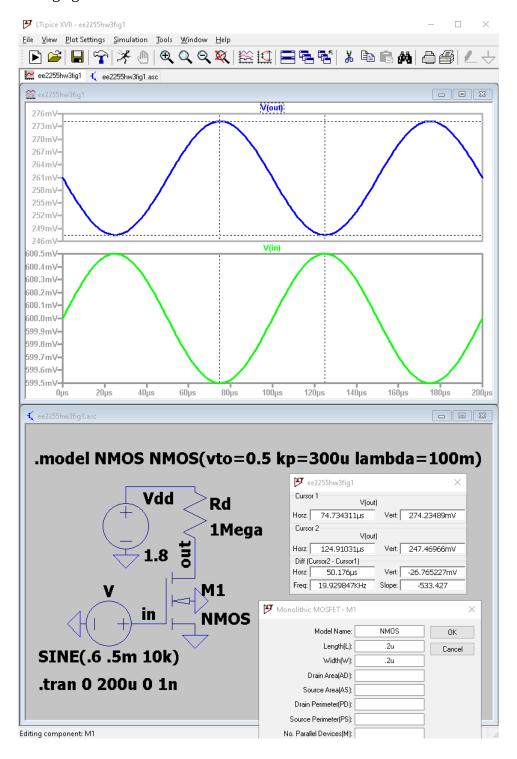
1. (a)

 $W = L = 0.2 \ \mu m$ Gate bias = 0.6 V Loading resistor = 1 M Ω Voltage gain = 26.765 > 10



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1. (b)

 $Vds = 0.260869 \ V \\ Vgs = 0.6 \ V \\ Vth = 0.5 \ V \\ 0.260869 > 0.6 - 0.5 \\ NMOS \ is in saturation region$

```
--- Operating Point ---
V(n001):
               1.8
                              voltage
V(out):
               0.260869
                              voltage
                              voltage
V(in):
               0.6
               1.53913e-006
                              device current
Id(M1):
                              device current
Ig(M1):
               0
Ib (M1):
               -2.70869e-013 device_current
Is(M1):
               -1.53913e-006 device_current
I (Rd):
               1.53913e-006 device current
               -1.53913e-006 device current
I (Vdd):
                              device_current
I(V):
```

1. (c)

$$I_{D} = \frac{1}{2} \mu_{n} C_{OX} \frac{W}{L} (V_{GS} - V_{TH})^{2} (1 + \lambda V_{DS})$$

$$I_{D} = \frac{1}{2} 300 \cdot 10^{-6} \frac{0.2 \cdot 10^{-6}}{0.2 \cdot 10^{-6}} (0.6 - 0.5)^{2} (1 + 100 \cdot 10^{-3} \times V_{DS}) \quad 0$$

$$V_{Ad} - V_{DS} = I_{D} R_{D}$$

$$1.8 - V_{DS} = I_{D} \cdot 10^{6} \quad 2$$

$$P_{D} = \left[\frac{\partial}{\partial V_{DS}} I_{D}\right]^{-1}$$

$$P_{D} = \left[\frac{\partial}{\partial V_{DS}} I_{D}\right]^{-1}$$

$$\gamma_{0} = \left[\frac{\partial}{\partial V_{DS}} I_{D} \right]^{-1} \\
= \left[\frac{1}{2} \mu_{n} C_{OX} \frac{W}{L} (V_{GS} - V_{TH})^{2} \lambda \right]^{-1} \\
= \left[\frac{1}{2} 300 \cdot 10^{-6} \frac{0.2 \cdot 10^{-6}}{0.2 \cdot 10^{-6}} (0.6 - 0.5)^{2} 100 \cdot 10^{-3} \right]^{-1}$$

1. (d)

$$g_{m} = \frac{\partial}{\partial V_{GS}} I_{p}$$

$$= \frac{\partial}{\partial V_{GS}} \left[\frac{1}{2} \mu_{n} C_{OX} \frac{W}{L} (V_{GS} - V_{TH})^{2} (1 + \lambda V_{pS}) \right]$$

$$= \mu_{n} C_{OX} \frac{W}{L} (V_{GS} - V_{TH}) (1 + \lambda V_{pS})$$

$$= 300 \cdot 10^{-6} \frac{0.2 \cdot 10^{-6}}{0.2 \cdot 10^{-6}} (0.6 - 0.5) (1 + 100 \cdot 10^{-3} \times 0.26087)$$

$$= 0.00003078261 \Omega^{-1}$$

$$A_{V} = -g_{m} (R_{p} || r_{o})$$

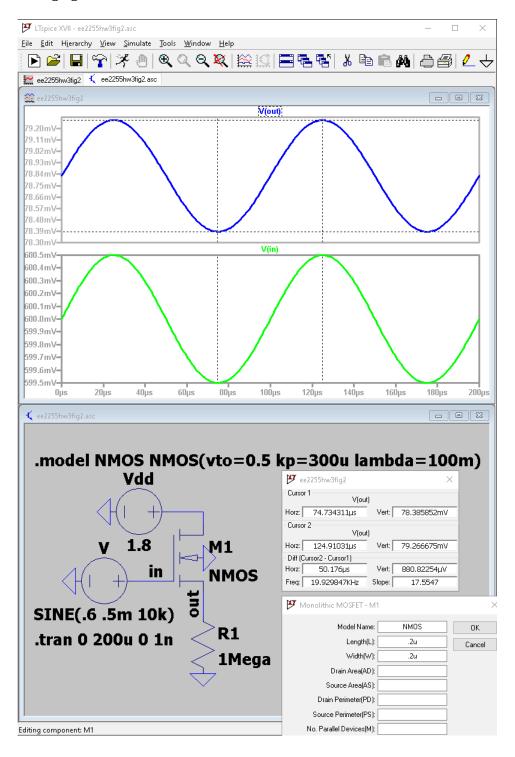
$$= -0.00003078261 \times \frac{10^{6} \times 6666667}{10^{6} + 6666667}$$

$$= -26.767$$

26.765 和 26.767 的誤差為 0.7‰ 很準確

2. (a)

 $W = L = 0.2 \ \mu m$ Gate bias = 0.6 V Loading resistor = 1 M Ω Voltage gain = 0.88082 > 0.8



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2. (b)

```
Vds = 1.8 - 0.078826 = 1.721174 (V)
Vgs = 0.6 - 0.078826 = 0.521174 (V)
Vth = 0.5 V
1.721174 > 0.521174 - 0.5
NMOS is in saturation region
```

```
--- Operating Point ---
V(n001):
               1.8
                              voltage
V(in):
               0.6
                              voltage
               0.0788262
                              voltage
V(out):
               7.88282e-008
                              device current
Id(M1):
                              device current
Iq(M1):
               0
Ib (M1):
               -1.89835e-012 device current
Is(M1):
               -7.88263e-008 device_current
I(R1):
               7.88262e-008 device current
               -7.88281e-008 device current
I (Vdd) :
                              device current
I(V):
```

2. (c)

$$V_{DD} = V_{ps} + V_{s}$$

$$1.8 = V_{Ds} + V_{s} \quad \Phi$$

$$V_{s} = I_{D} \times R_{s}$$

$$V_{s} = I_{D} \times 10^{b} \quad \Phi$$

$$I_{D} = \frac{1}{2} \mu_{n} Cox \frac{W}{L} (V_{as} - V_{TH})^{2} (1 + \lambda V_{ps})$$

$$I_{D} = \frac{1}{2} 300 \cdot 10^{-b} \frac{0.2 \cdot 10^{-b}}{0.2 \cdot 10^{-b}} (0.b - V_{s} - 0.5)^{2} (1 + 100 \cdot 10^{-3} V_{ps}) \quad \Im$$

$$r_{0} = \left[\frac{\partial}{\partial V_{pS}} I_{D}\right]^{-1}$$

$$= \left[\frac{1}{2} \mu_{n} C_{OX} \frac{W}{L} \left(V_{G} - V_{S} - V_{TH}\right)^{2} \lambda\right]^{-1}$$

$$= \left[\frac{1}{2} 300 \cdot 10^{-6} \frac{0.2 \cdot 10^{-6}}{0.2 \cdot 10^{-6}} \left(0.6 - 0.078826 - 0.5\right)^{2} 100 \cdot 10^{-3}\right]^{-1}$$

$$= 1.48697 \cdot 10^{8}$$

2. (d)

$$g_{m} = \frac{\partial}{\partial V_{GS}} I_{D}$$

$$= \mu_{K} C_{OX} \frac{W}{L} \left(V_{G} - V_{S} - V_{TH} \right) \left(1 + \lambda V_{DS} \right)$$

$$= 300 \cdot 10^{-6} \frac{0.2 \cdot 10^{-6}}{0.2 \cdot 10^{-6}} \left(0.6 - 0.078826 - 0.5 \right) \left(1 + 100 \cdot 10^{-3} \times 1.72117 \right)$$

$$= 7.4 + 55 \cdot 10^{-6}$$

$$A_{V} = \frac{R_{D} \parallel r_{o}}{g_{m}^{-1} + \left(R_{D} \parallel r_{o} \right)}$$

$$= \frac{10^{b} \times 1.48697 \cdot 10^{8}}{10^{b} + 1.48697 \cdot 10^{8}}$$

$$= 0.88089$$

0.88082 和 0.88089 的誤差為 0.8‱ 很準確